



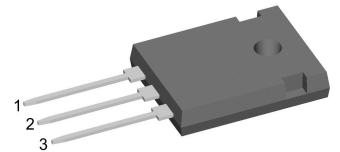
HiPerFRED²

$V_{RRM} = 300\text{ V}$
 $I_{FAV} = 2 \times 30\text{ A}$
 $t_{rr} = 55\text{ ns}$

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DPF60C300HB



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm}-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

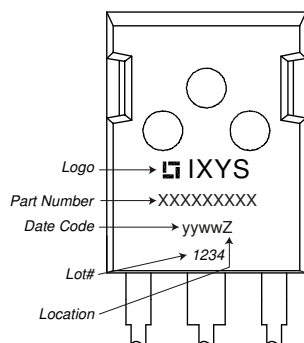


Fast Diode				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			300	V	
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			300	V	
I_R	reverse current, drain current	$V_R = 300 V$	$T_{VJ} = 25^{\circ}C$		5	μA	
		$V_R = 300 V$	$T_{VJ} = 150^{\circ}C$		0.25	mA	
V_F	forward voltage drop	$I_F = 30 A$	$T_{VJ} = 25^{\circ}C$		1.16	V	
		$I_F = 60 A$			1.34	V	
		$I_F = 30 A$	$T_{VJ} = 150^{\circ}C$		0.97	V	
		$I_F = 60 A$			1.18	V	
I_{FAV}	average forward current	$T_C = 145^{\circ}C$ rectangular $d = 0.5$	$T_{VJ} = 175^{\circ}C$		30	A	
V_{FO}	threshold voltage	} for power loss calculation only	$T_{VJ} = 175^{\circ}C$		0.72	V	
r_F	slope resistance				6.7	m Ω	
R_{thJC}	thermal resistance junction to case				0.95	K/W	
R_{thCH}	thermal resistance case to heatsink			0.3		K/W	
P_{tot}	total power dissipation		$T_C = 25^{\circ}C$		160	W	
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$		400	A	
C_J	junction capacitance	$V_R = 150 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		42	pF	
I_{RM}	max. reverse recovery current	} $I_F = 30 \text{ A}; V_R = 200 \text{ V}$ $-di_F / dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^{\circ}C$		6	A	
			$T_{VJ} = 125^{\circ}C$		10	A	
t_{rr}	reverse recovery time		$T_{VJ} = 25^{\circ}C$		55	ns	
			$T_{VJ} = 125^{\circ}C$		85	ns	



Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			50	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

Product Marking



Part description

- D = Diode
- P = HiPerFRED
- F = ultra fast
- 60 = Current Rating [A]
- C = Common Cathode
- 300 = Reverse Voltage [V]
- HB = TO-247AD (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPF60C300HB	DPF60C300HB	Tube	30	506882

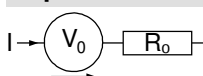
Similar Part	Package	Voltage class
DPG60C300HB	TO-247AD (3)	300
DPG60C300QB	TO-3P (3)	300
DPG60C300PC	TO-263AB (D2Pak) (2)	300
DPG60C300HJ	ISOPLUS247 (3)	300

DPG80C300HB	TO-247AD (3)	300
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Equivalent Circuits for Simulation

** on die level*

$T_{VJ} = 175^{\circ}C$



Fast Diode

$V_{0\ max}$ threshold voltage

0.72

V

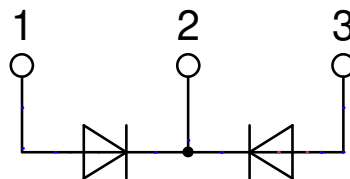
$R_{0\ max}$ slope resistance *

4.1

mΩ



Outlines TO-247



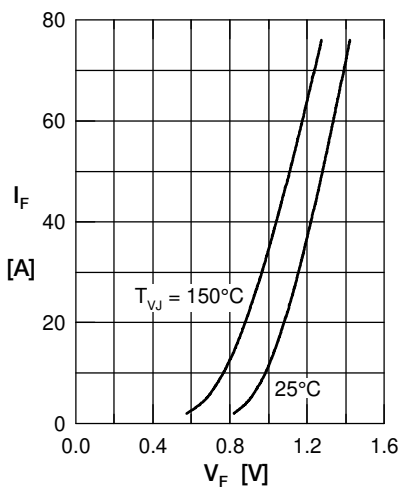
Fast Diode


Fig. 1 Forward current I_F versus V_F

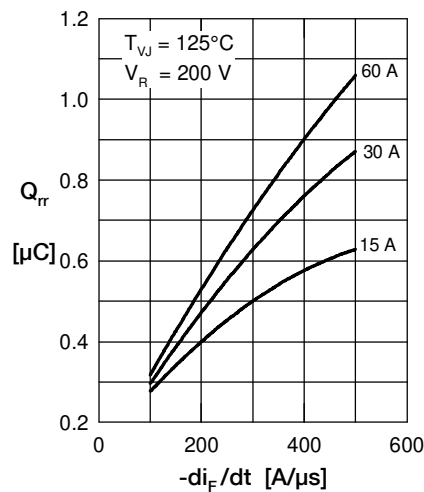


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

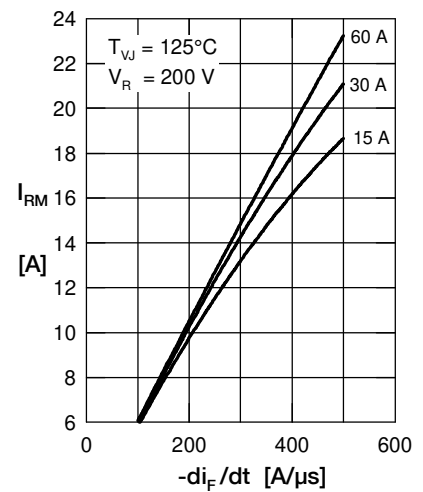


Fig. 3 Typ. reverse recov. current I_{RM} versus $-di_F/dt$

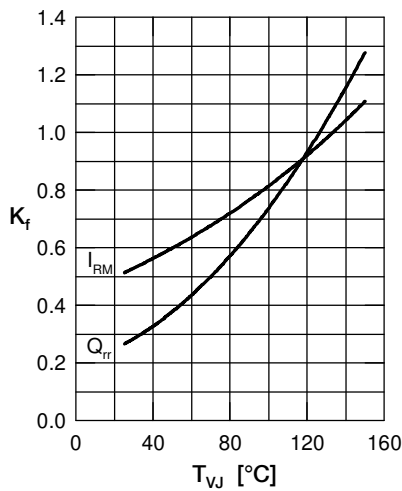


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

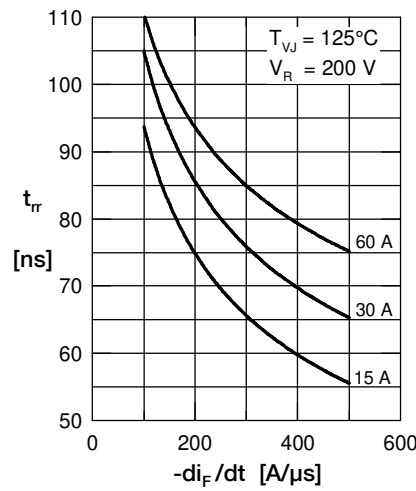


Fig. 5 Typ. reverse recov. time t_{rr} versus $-di_F/dt$

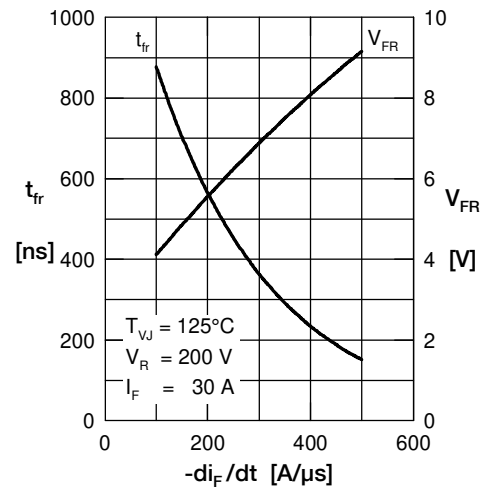


Fig. 6 Typ. forward recovery voltage V_{FR} & time t_{fr} versus di_F/dt

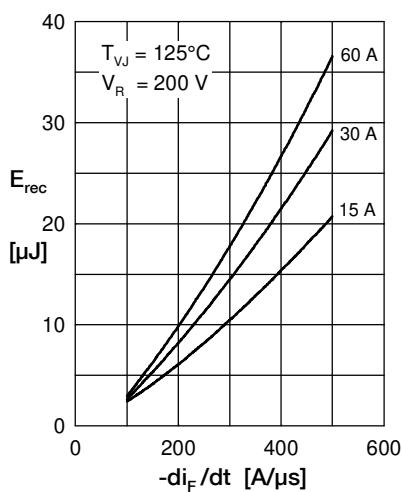


Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$

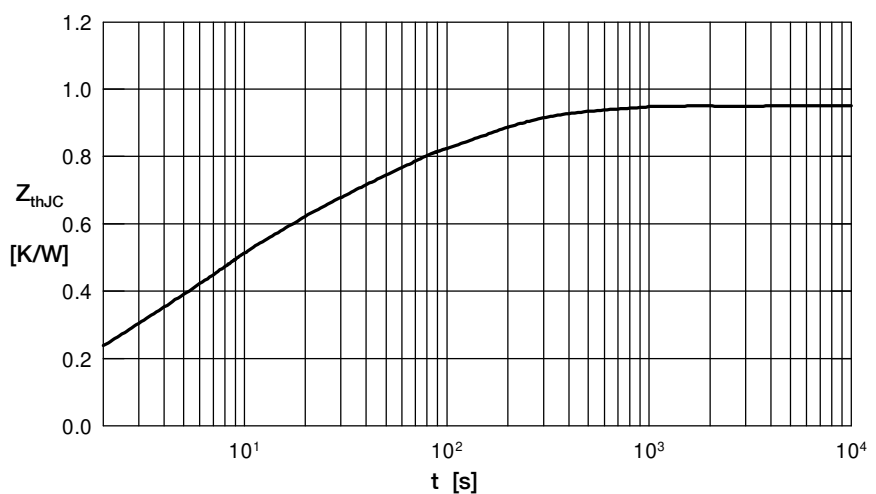


Fig. 8 Transient thermal impedance junction to case